

Multistage Amplifier Frequency Response

- Summary of frequency response of single-stages:

CE/CS: suffers from Miller effect

CC/CD: “wideband” -- see Section 10.5

CB/CG: “wideband” -- see Section 10.6

(wideband means that the stage operates to near the frequency limit of the device ... f_T)

- How to find the Bode plot for a general multistage amplifier?

can't handle n poles and m zeroes analytically --> SPICE

develop analytical tool for an important special case:

* **no zeroes**

* **exactly one “dominant” pole** ($\omega_1 \ll \omega_2, \omega_3, \dots, \omega_n$)

$$\frac{V_{out}}{V_{in}} = \frac{A_o}{(1 + j(\omega/\omega_1))(1 + j(\omega/\omega_2))(\dots)(1 + j(\omega/\omega_n))}$$

(the example shows a voltage gain ... it could be I_{out}/V_{in} or V_{out}/I_{in})

Finding the Dominant Pole

- Multiplying out the denominator:

$$\frac{V_{out}}{V_{in}} = \frac{A_o}{1 + b_1 j\omega + b_2 (j\omega)^2 + \dots + b_n (j\omega)^n}$$

The coefficient b_1 originates from the sum of $j\omega/\omega_i$ factors --

$$b_1 = \frac{1}{\omega_1} + \frac{1}{\omega_2} + \dots + \frac{1}{\omega_n} = \sum_i^n \frac{1}{\omega_i} \approx \frac{1}{\omega_1}$$

Therefore, if we can estimate the linear coefficient b_1 in the denominator polynomial, we can estimate of the dominant pole

Procedure: see P. R. Gray and R. G. Meyer, *Analysis and Design of Analog Integrated Circuits*, 3rd ed., Wiley, 1994, pp. 502-504.

1. Find circuit equations with current sources driving each capacitor
2. Denominator polynomial is determinant of the matrix of coefficients
3. b_1 term comes from a sum of terms, each of which has the form:

$$R_{Tj} C_j$$

where C_j is the j^{th} capacitor and R_{Tj} is the Thévenin resistance across the j^{th} capacitor terminals (with all capacitors open-circuited)

Open-Circuit Time Constants

- The dominant pole of the system can be estimated by:

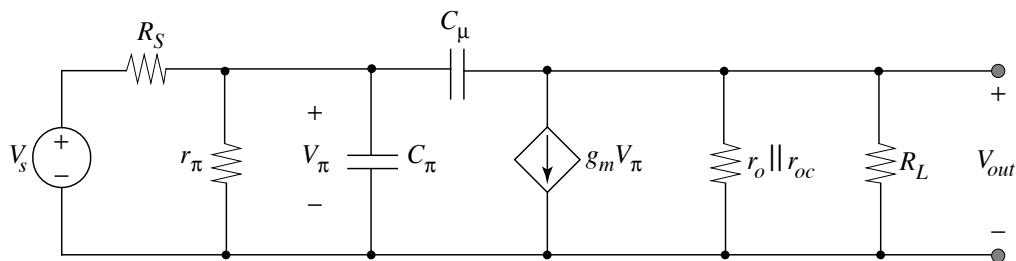
$$\omega_1 \approx \frac{1}{b_1} = \left(\sum_j^n R_{Tj} C_j \right)^{-1} = \left(\sum_1^n \tau_j \right)^{-1},$$

where $\tau_j = R_{Tj} C_j$ is the **open-circuit time constant** for capacitor C_j

- This technique is valuable because it estimates the contribution of each capacitor to the dominant pole frequency *separately* ... which enables the designer to understand what part of a complicated circuit is responsible for limiting the bandwidth of the amplifier.

Example: Revisit CE Amplifier

- Small-signal model:



- Apply procedure to each capacitor separately

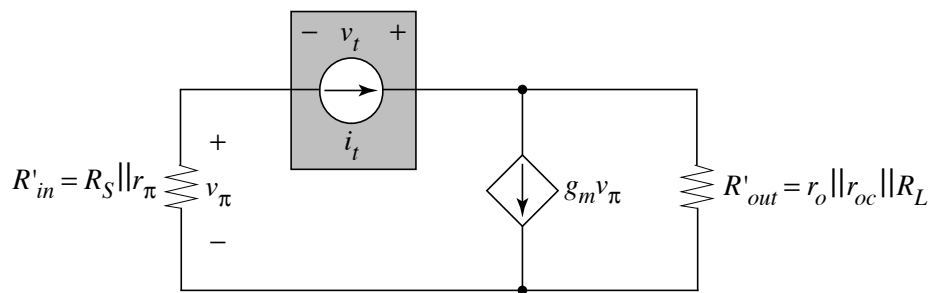
1. C_π 's Thévenin resistance is found by inspection as the resistance across its terminals with all capacitors open-circuited:

$$R_{T\pi} = R_S \parallel r_\pi = R_{in}' \rightarrow \tau_{C_{\pi o}} = R_{T\pi} C_\pi$$

2. C_μ 's Thévenin resistance is *not* obvious \rightarrow must use test source and network analysis

Time Constant for C_μ

- Circuit for finding $R_{T\mu}$



v_π is given by:

$$v_\pi = -i_t(R_S || r_\pi) = -i_t R'_{in}$$

v_o is given by:

$$v_o = -i_o R'_{out} = (i_t - g_m v_\pi) R'_{out} = i_t (g_m R'_{in} + 1) R'_{out}$$

v_t is given by:

$$v_t = v_o - v_\pi = i_t ((1 + g_m R'_{in}) R'_{out} + R'_{in})$$

solving for $R_{T\mu} = v_t / i_t$

$$R_{T\mu} = R'_{in} + R'_{out} + g_m R'_{in} R'_{out}$$

$$\tau_{C_{\mu o}} = R_{T\mu} C_\mu = (R'_{in} + R'_{out} + g_m R'_{in} R'_{out}) C_\mu$$

Estimate of Dominant Pole for CE Amplifier

- Estimate dominant pole as inverse of sum of open-circuit time constants

$$\omega_1^{-1} = (R_{T\pi}C_\pi + R_{T\mu}C_\mu) = R_{in}'C_\pi + (R_{in}' + R_{out}' + g_m R_{in}'R_{out}')C_\mu$$

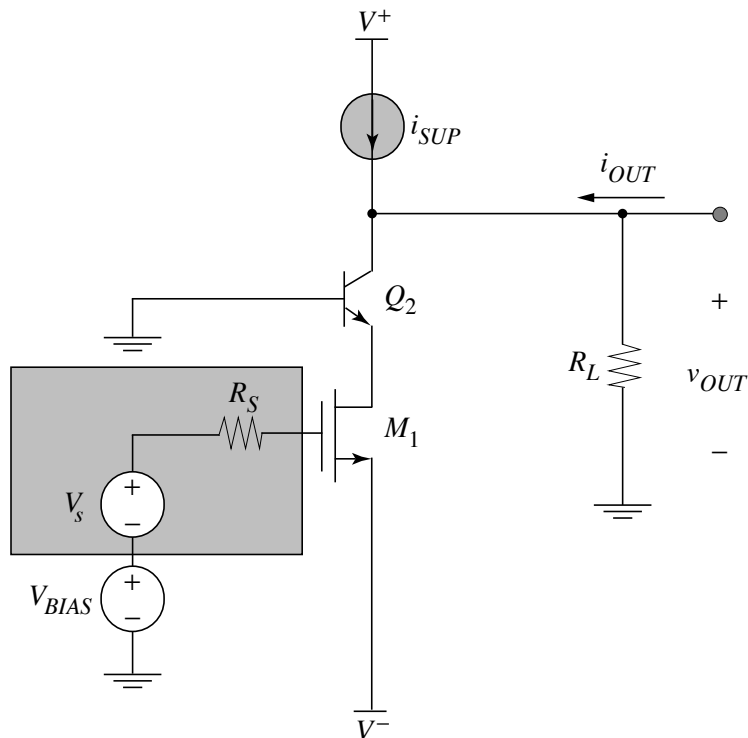
inspection --> identical to “exact” analysis (which also assumed $\omega_1 \ll \omega_2$)

- Advantage of open-circuit time constants: *general* technique

Example: include C_{cs} and estimate its effect on ω_1

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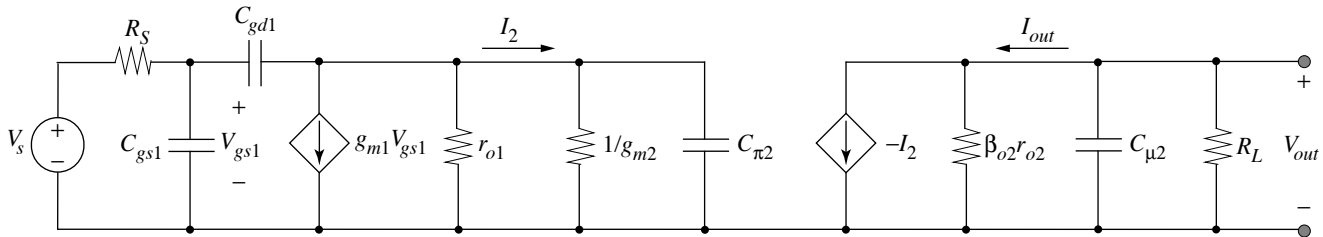
- Applying the open-circuit time constant technique to find the dominant pole frequency -- use CS/CB cascode as an example



- Systematic approach:
 1. two-port small-signal models for each stage (*not* the device models!)
 2. carefully add capacitances across the appropriate nodes of two-port models, which may not correspond to the familiar device configuration for some models

Two-Port Model for Cascode

- The base-collector capacitor $C_{\mu 2}$ is located between the output of the CB stage (the collector of Q_2) and small-signal ground (the base of Q_2)



We have omitted C_{db1} , which would be in parallel with $C_{\pi 2}$ at the output of the CS stage, and C_{cs2} which would be in parallel with $C_{\mu 2}$. In addition, the current supply transistor will contribute additional capacitance to the output node.

- Time constants

$$\tau_{C_{gs1o}} = R_S C_{gs1}$$

$$\tau_{C_{gd1o}} = (R_{in}' + R_{out}' + g_{m1} R_{in}' R_{out}') C_{gd1}$$

where $R_{in}' = R_S$ and $R_{out}' = r_{o1} \parallel \left(\frac{1}{g_{m2}} \right) \approx \frac{1}{g_{m2}}$

Since the output resistance is only $1/g_{m2}$, the Thévenin resistance for C_{gd1} is not magnified (i.e., the Miller effect is minimal):

$$\tau_{C_{gd1o}} = \left(R_S + \frac{1}{g_{m2}} + \left(\frac{g_{m1}}{g_{m2}} \right) R_S \right) C_{gd1} \approx R_S (1 + g_{m1}/g_{m2}) C_{gd1}$$

Cascode Frequency Response (cont.)

- The base-emitter capacitor of Q_2 has a time constant of

$$\tau_{C_{\pi 2o}} = \left(\frac{1}{g_{m2}}\right)C_{\pi 2}$$

- The base-collector capacitor of Q_2 has a time constant of

$$\tau_{C_{\mu 2o}} = (\beta_{o2}r_{o2} || r_{oc} || R_L)C_{\mu 2} \approx R_L C_{\mu 2}$$

- Applying the theorem, the dominant pole of the cascode is approximately

$$\omega_{3db}^{-1} \approx \tau_{C_{gs1o}} + \tau_{C_{gd1o}} + \tau_{C_{\pi 2o}} + \tau_{C_{\mu 2o}}$$

$$\omega_{3db}^{-1} \approx R_S C_{gs1} + R_S (1 + g_{m1}/g_{m2}) C_{gd1} + \left(\frac{1}{g_{m2}}\right) C_{\pi 2} + R_L C_{\mu 2}$$

Gain-Bandwidth Product

- A useful metric of an amplifier's frequency response is the product of the low-frequency gain $|A_{vo}|$ and the 3 dB frequency ω_{3dB}

For the cascode, the gain is $|A_{vo}| = |g_{m1}R_L|$ and the gain-bandwidth product is

$$|A_{vo}|\omega_{3dB} \approx \frac{g_{m1}R_L}{R_S C_{gs1} + R_S(1 + g_{m1}/g_{m2})C_{gd1} + \left(\frac{1}{g_{m2}}\right)C_{\pi2} + R_L C_{\mu2}}$$

- If the voltage source resistance is small, then

$$|A_{vo}|\omega_{3dB} \approx \frac{g_{m1}R_L}{(C_{\pi2}/g_{m2} + R_L C_{\mu2})}$$

which has the same form as the common-base gain-bandwidth product (and which is *much* greater than the Miller-degraded common-source)